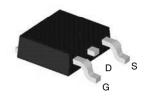
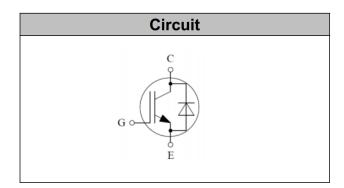


TO-252 Pin Configuration



Top View



IGBT Discrete

V _{CE}	600	V
I _C (T _C =100°C)	10	A
V _{CE(SAT)} I _C =10 A	1.8	V

Applications

- · Inverter for motor drive
- · AC and DC servo drive amplifier
- Uninterruptible power supply

Features

- High breakdown voltage to 600V for improved reliability
- Maximum junction temperature 150 °C
- · Positive temperature coefficient
- . Including fast & soft recovery anti-parallel FWD
- High short circuit capability(10us)

Maximum Ratings

Parameter	Symbol	Value	Unit
Collector-Emitter Breakdown Voltage	V_{CE}	600	V
DC Collector Current, limited by T_{jmax} $T_C = 25^{\circ}C$ $T_C = 100^{\circ}C$	$ m I_{C}$	20 10	A
Diode Forward Current, limited by T_{jmax} T_{C} = 25°C T_{C} = 100°C	I_{F}	20 10	A
Continuous Gate-Emitter Voltage	$ m V_{GE}$	±25	V
Pulsed Collector Current, V_{GE} =15V, tp limited by T_{jmax}	I _{CM}	30	A
Power Dissipation , Tc=25°C	P _{tot}	82	W
Operating Junction Temperature	$T_{\rm j}$	-55+150	°C
Storage Temperature	T_{s}	-55+150	°C
Soldering Temperature, wave soldering 1.6mm(0.063in.) from case for 10s		300	°C

Rev.1.0



Thermal Resistance

Parameter	Symbol	Max. Value	Unit
IGBT Thermal Resistance, Junction - Case	R _{th} (j-c)	1.52	K/W
Diode Thermal Resistance, Junction - Case	R _{th} (j-c)	2.16	K/W
Thermal Resistance, Junction - Ambient	R _{th} (j-a)	65	K/W

Electrical Characteristics of the IGBT $(T_j=25^{\circ}Cunless otherwise specified)$:

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-Emitter Breakdown Voltage	BV _{CES}	V _{GE} =0V, I _C =250μA	600	-	-	V
Gate Threshold Voltage	$V_{\text{GE(th)}}$	$V_{GE}=V_{CE}, I_{C}=250\mu A$	4.5	-	6.5	V
Collector-Emitter Saturation Voltage	V _{CE(sat)}	V _{GE} =15V, I _C =10 A T _j =25°C, T _j =125°C		1.8 2.0	2.1	V
Zero Gate Voltage Collector Current	I _{CES}	V _{CE} =600V, V _{GE} =0V T _j = 25°C, T _j =125°C		- -	10 100	uA
Gate-Emitter Leakage Current	I _{GES}	V_{CE} = 0V, V_{GE} = ± 25V	-	-	200	nA
Input Capacitance	Cies		-	369	-	
Output Capacitance	Coes	V_{CE} = 25V, V_{GE} = 0V, f = 1MHz	-	37	-	pF
Reverse Transfer Capacitance	C _{res}		-	9.5	-	
Gate Charge	Q _G		-	15	-	
Gate-Emitter Charge	Q _{GE}	V _{CC} =300V,I _C =10A, V _{GE} =15V	-	2.9	_	nC
Gate-Collector Charge	Q _{GC}		-	6.8	-	



Switching Characteristic, Inductive Load (T_j= 25 °C unless otherwise specified):

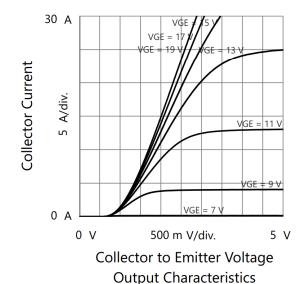
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Turn-on Delay Time	t _{d(on)}		-	14	-	ns
Rise Time	$t_{\rm r}$		-	12	-	ns
Turn-on Energy	Eon	$V_{CC} = 400V, I_{C} = 10A, V_{GE} = 15V$	-	0.09	-	mJ
Turn-off Delay Time	$t_{d(off)}$	$R_g=5\Omega$	-	18	-	ns
Fall Time	t_{f}		-	82	-	ns
Turn-off Energy	E _{off}		-	0.21	-	mJ

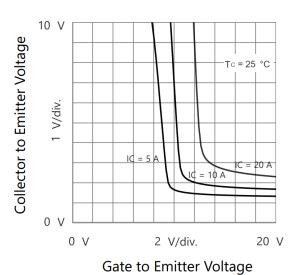
Electrical Characteristics of the DIODE $(T_j=25^{\circ}Cunless otherwise specified)$:

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Diode Forward Voltage	V_{F}	$I_F = 10A$	-	1.5	-	V
Reverse Recovery Time	T_{rr}	I _F =10A, di/dt= 200A/μs	-	43	-	ns
Reverse Recovery Charge	Qrr	1F-10A, di/dt-200A/μs	-	40	-	nC

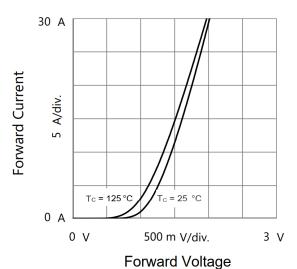


TYPICAL CHARACTERISTICS(25 °C, unless otherwise noted)

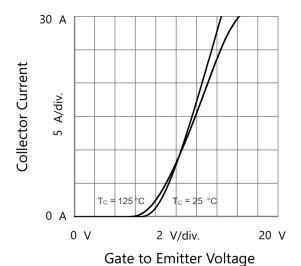




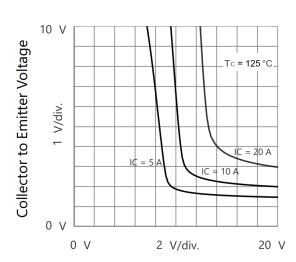
Collector to Emitter Voltage vs. Gate to Emitter Voltage



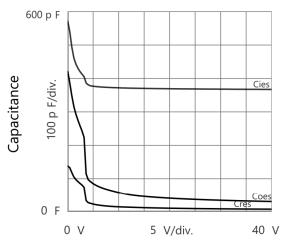
Freewheeling Diode Forward Characteristice



Transfer Characteristics



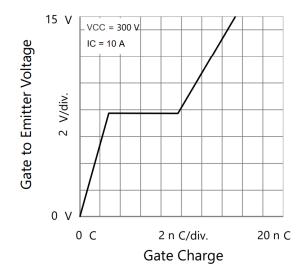


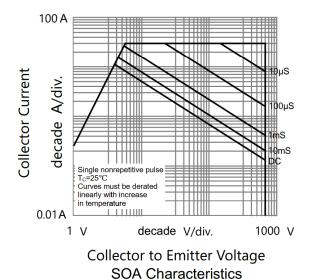


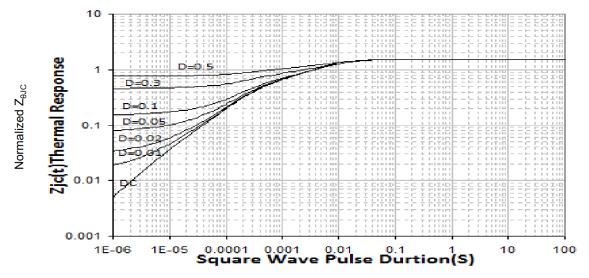
Collector to Emitter Voltage Capacitances



TYPICAL CHARACTERISTICS(25 °C, unless otherwise noted)

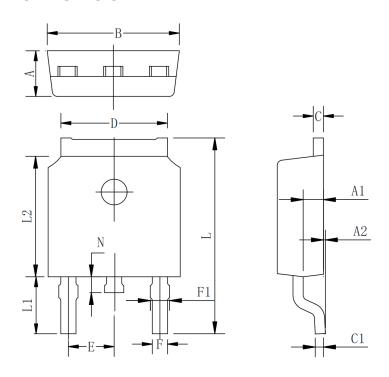






Pulse Width (S)
Figure 19: Normalized Maximum Diode Transient
Thermal Impedance

TO-252-2L PACKAGE OUTLINE



COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

Symbol	Min	Тур	Max		
A	2.10	2.30	2.50		
A1	0.88	1.01	1.16		
A2	0.00	0.15	0.28		
В	6.40	6.60	6.80		
C	0.42	0.50	0.63		
C1	0.42	0.50	0.63		
D	5.08	5.32	5.65		
Е	2.286 TYP				
F	0.63	0.76	0.89		
F1	0.64	0.86	1.08		
L	9.30	9.90	10.80		
L1	2.4	2.8	3.6		
L2	5.90	6.10	6.55		
N	0.57	0.80	1.05		



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